

DEFENCE SYSTEMS

The ERF-SFFPA-0002 is ideal for:

TYPICAL APPLICATIONS

- Electronic Warfare/Countermeasures
- Broadband Mobile Jamming Applications
- Airborne, Aircraft and UAV Equipment
- Power Amplifier Stage for Wireless Infrastructure
- Test and Measurement Equipment
- General Purpose Broadband Transmitter Amplification

GENERAL DESCRIPTION

The ERF-SFFPA-0002 is a solid-state, Class AB broadband power amplifier module based on advanced GaN HEMT technology. The ERF-SFFPA-0002 is ideal for pulsed or CW applications, offering exceptional performance and functionality in a small and lightweight form factor. The design employs proprietary matching networks and combining techniques that ensure optimum performance at low cost. Advanced and unique features are accessible via an FPGA-based serial interface. Alternatively or in addition, the module may be fully controlled by the discrete I/O interface.

PRODUCT FEATURES

Small Form Factor (180 x 90 x 16 mm): Half the Height and Volume Compared with Competing Models

100W 420MHz TO 2700MHz

Exceptional Bandwidth, Output Power and Efficiency

Ultra-Fast and Effective Mute Function

Comprehensive Built-In Test, Telemetry and Protection

High-Resolution Gain Control

Supports Internally-Stored Calibration Look-Up Tables

High Reliability and Ruggedness

Innovative Space-Saving Connector System



ELECTRICAL CHARACTERISTICS $T_c = +25$ °C, 28 VDC, 50 Ω System (unless otherwise noted)

PARAMETER	MIN	TYP	MAX	UNITS
Operating Frequency Range			2700	MHz
Rated Output Power CW (ROP)	48.5		dBm	
Saturated Output Power (P _{SAT})	48.5	49.3	50.5	dBm
Power-Added Efficiency @ ROP (PAE)	35	39		%
Small Signal Gain (S ₂₁)	53		57	dB
Input Return Loss	15			dB
Output Return Loss	10			dB
Input Power @ ROP	-5		2	dBm
Input Power @ P _{SAT}			5	dBm
Gain Flatness @ ROP [1]	-0.25		0.25	dB
Noise Figure (NF)			22	dB
Output Third-Order Intercept Point (OIP ₃) [2]				dBm
Second Harmonic Emissions @ P _{SAT}			-14	dBc
Third Harmonic Emissions @ P _{SAT}			-17	dBc
Higher Harmonic Emissions @ P _{SAT}			-22	dBc
Non-Harmonic Spurious Emissions		-65	-60	dBc
DC Supply Voltage [3]		28.0	28.5	V
Current Consumption @ P _{SAT} [4]		7.1	9.2	Α
Mute / Enable Mode Switching Characteristics:				
t _{ENABLE} , t _{MUTE} (50% CTRL to 10/90% RF)		700	1000	ns
Isolation in Mute Mode [6]		80		dB
Output Noise Floor in Mute Mode [6] [7]		-165	-140	dBm/Hz
Current Consumption in Mute Mode		175	200	mA
Gain Control Characteristics:				
Full-Scale Gain Reduction (Relative to Default)		34.5		dB
Adjustment Resolution		0.25		dB

^[1] Measured in any 5 MHz sub-band at a given temperature. Relative to sub-band centre frequency.

^[2] Measured at+20 dBm/tone, 1 MHz tone spacing.

^[3] For no performance degradation. Also see Absolute Maximum Ratings.

^[4] At 28V DC supply voltage.



100W 420MHz TO 2700MHz

[5] Quiescent current (I_{DQ}).

[6] Over the frequency range 10 MHz to 10 GHz.

[7] Assumes noise floor at RF input ≤-144 dBm/Hz.

CONTROL CHARACTERISTICS AND ADVANCED FEATURES [8]

PARAMETER	VALUE		
Ultra-Fast Mute / Enable Switching	See Electrical Characteristics and Absolute Maximum Ratings		
	Control via Discrete Input [9]		
Serial Communications Interface	2-wire serial interface required to access most advanced features		
(High Noise Immunity)	Interface: RS-485 Half Duplex		
	Data Rate: 1 Mbps		
	Also see Re-Mappable I/O Pins		
High-Resolution Gain Control	See Electrical Characteristics and Absolute Maximum Ratings		
	Control via Serial Comms Interface		
	Limited Discrete Control via Re-Mappable I/O Pins [9]		
User Memory	16 MB (128 Mbit) Serial Flash Memory Allocation		
	Supports multiple Calibration Tables or User-Specific Data		
	Control via Serial Comms Interface		
	Limited Discrete Control via Re-Mappable I/O Pins [9]		
Built-In Test Functions	Power-On BIT (PBIT)		
	Continuous BIT (CBIT)		
	Initiated BIT (IBIT)		
	All BIT data is accessible via the Serial Comms Interface		
Temperature BIT (P/C/I)	Baseplate and core temperatures monitored		
	Range: -40 °C to +125 °C		
	Accuracy: ±3 °C		
Voltage BIT (P/C/I)	All critical voltage rails monitored		
	Accuracy: ±5 %		
Current BIT (P/C/I)	Critical device currents and total input current monitored		
	Accuracy: ±5 %		
Memory Integrity BIT (P/I)	CRC checking of User Data and Factory Data		
Alarm Output	Discrete Output [9]		
	Logical OR status of individual BIT flags		
	Behaviour may be modified or disabled via Serial Comms Interface		
Elapsed On-Time Recorder	34 Years of Total (Power-On) Time Accumulation		
	17-Bit Power-Up Event Counter		
Electronic Identification Data (Non-Volatile)	Part number		
	Serial Number		
	Revision		
Thermal Overload Protection	Threshold: +90 ±3 °C		
	Hysteresis (T _{MUTE} - T _{ENABLE}): 8 °C typ.		
	Behaviour may be modified or disabled via Serial Comms Interface		
Re-Mappable I/O Pins [9]	Up to 4 discrete I/O pins with re-configurable functionality.		
	Applications may include:		
	Add SPI Bus or RS232 as the Serial Communications Interface		
	Event triggers or encoded address bits to cycle between or		
	select pre-programmed calibration settings in timing-critical		
	situations		

[8] Control Interface is described fully in the Interface Control Document for SFF PA Module (Doc. No. 01-000-0004-01).

[9] I/O Pins are 3V3 TTL/CMOS compatible. Inputs are 5V tolerant.



100W 420MHz TO 2700MHz

MECHANICAL CHARACTERISTICS

PARAMETER	VALUE	UNITS
Dimensions [10]	180 x 90 x 16	mm
Mass	430 ±20	g
RF In / Out Connectors	SMA Female	-
DC In / Control Connector [11]	Mixed Technology Male – 2 Power + 8 Signal	-
Cooling Method	External Heatsink to Baseplate (Not Supplied)	-

^[10] Also see Outline Drawing.

ENVIRONMENTAL CHARACTERISTICS

PARAMETER		TYP	MAX	UNITS
Case or Baseplate Temperature			+85	°C
Humidity (MIL-STD-810F, Method 507.4, para. 4.5.2) [13]		95	%	
Altitude (MIL-STD-810F, Method 500.4, para. 4.5.2, 4.5.3) [13] 30,000		30,000	ft	
Vibration (MIL-STD-810F, Method 514.5, para. 4.5.2) [13]	Operational – Aircraft & Ground		-	
Shock (MIL-STD-810F, Method 516.5, para. 4.5.2.3) [13] 40		40	g's	
Ingress Protection	IP51		-	

^[12] Includes Cold Start after ≥2 hour Cold Soak.

ABSOLUTE MAXIMUM RATINGS (Not simultaneous)

(Continued of the continued of the conti			
RF Input Power	+15 dBm		
RF Output Mismatch	VSWR ∞:1 at all phase angles		
Case or Baseplate Temperature (Operating)	-40 °C to +85 °C		
Case or Baseplate Temperature (Non-Operating)	-40 °C to +100 °C		
DC Supply Voltage (DC IN+ to GND)	24V to 32V		
Control Interface (I/O and RS485-HD to GND)	-0.5V to 5.5V		
Mute / Enable Mode Switching Frequency	40 kHz		
Gain Control Setting Update Frequency	25 kHz		
ESD Sensitivity [13]	HBM Class 1A		

Exceeding maximum ratings may cause permanent damage. Operation between operating range maximum and absolute maximum for extended periods may reduce device reliability. Absolute maximum ratings are stress figures only and functional operation under these conditions is not implied.

ESD PRECAUTIONS

Although this product contains circuitry to protect it from damage due to ESD, when handling this product observe the same precautions as with any other ESD-sensitive device.

ROHS COMPLIANCE

RoHS compliant parts and processes are used in the manufacture of this product.



ECCN

The highest ECCN grading of any component used in the product is US Department of Commerce EAR99 (ITAR-free).

QUALITY

This product is designed and manufactured in the United Kingdom in accordance with the ISO 9001:2008 Quality Management System.



Part Number: 10-000-0002-XX Document: 01-200-0002-01 Revision: Preliminary

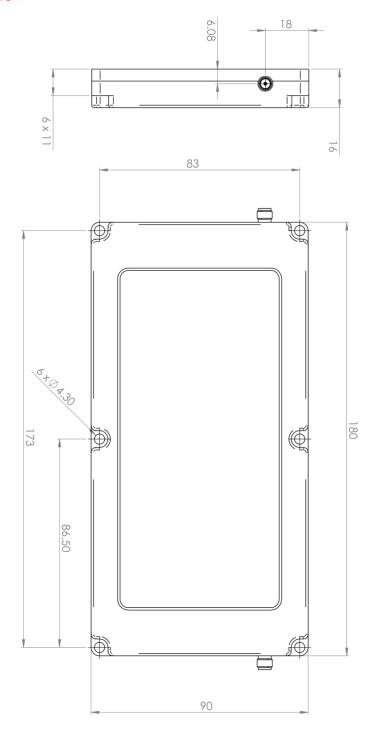
^[11] Please contact Antares for connector specifics.

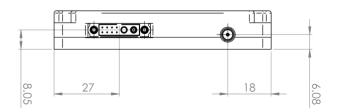
^[13] Designed to meet.



100W 420MHz TO 2700MHz

OUTLINE DRAWING





ERF-SFFA-0002



100W 420MHz TO 2700MHz

ORDERING INFORMATION

MODEL NAME	PART NUMBER	FINISH
ERF-SFFPA-0002	10-000-0002-01	Iridite ™ NCP

REVISION HISTORY

REVISION	DATE	CHANGE DESCRIPTION	ECN
Α			

Part Number: 10-000-0002-XX Document: 01-200-0002-01 Revision: Preliminary